TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TD62304APG,TD62304AFG TD62305APG,TD62305AFG

7CH LOW ACTIVE DARLINGTON SINK DRIVER

The TD62304APG/AFG and TD62305APG/AFG are non–inverting transistor arrays, which are comprised of eight NPN darlington buffer-transistor output stages and PNP input stages.

These devices can be operated by source input voltage and are suitable for operations with a 5-V general purposed logic IC such as 5-V TTL, 5-V CMOS and 5-V Microprocessor which have sink current output drivers.

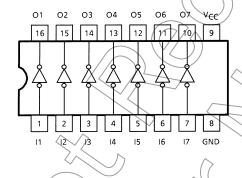
Please observe the thermal condition for using.

The suffix (G) appended to the part number represents a Lead (Pb)-Free product.

Features

- Output current (single output) 500 mA (Max.)
- High sustaining voltage 50 V (Min.)
- Low level active input
- Input compatible with 5-V TTL and 5-V CMQS
- Package type- APG: DIP-16 pin
- Package type- AFG: SOP-18 pin

Pin connection (top view)



TD62304APG TD62305APG DIP16-P-300-2.54A TD62305AFG TD62305AFG SOP16-P-225-1.27

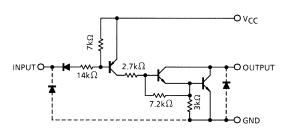
Weight DIP16-P-300-2.54A: 1.11 g (typ.) SOP16-P-225-1.27: 0.16 g (typ.)

Schematics (each driver)

TD62304APG/AFG

INPUT O $\frac{2.7k\Omega}{14k\Omega}$ O OUTPUT

TD62305APG/AFG



Note: The input and output parasitic diodes cannot be used as clamp diodes.



Absolute Maximum Ratings (Ta = 25°C)

CHARACTERISTICS	3	SYMBOL	RATING	UNIT	
Supply Voltage		V _{CC}	-0.5~7.0	V	
Output Sustaining Voltage		V _{CE} (SUS)	-0.5~50	>	
Output Current		I _{OUT}	500	mA / ch	
Input Valtage		VIN	-22~V _{CC} +0.5	< /	
Input Voltage		VIN	-0.5~7 (Note 1)	(
Input Current		I _{IN}	-10	mA	
Power Dissipation	APG	P _D	1.47	F)	
	AFG		0.625 (Note 2)		
Operating Temperature		T _{opr}	-40~85		
Storage Temperature		T _{stg}	-55~150	> °C	



Note 1: TD62305APG / AFG
Note 2: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

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Recommended Operating Conditions (Ta = -40~85°C and Ta = -30~75°C for only Type-P)

CHARACTERISTIC		SYMBOL	CONDITION	MIN	TYP.	MAX	UNIT		
Supply Voltage	Supply Voltage		V _{CC}	_	4.5	5.0	5.5	V	
Output Sustaining Voltage		V _{CE} (SUS)	-	7/^)r	50	V		
Output Current APG AFG				DC 1 Circuit		-	400		
		APG		T _{pw} = 25 ms, duty = 10% 7 circuits)° 0	-	350		
		AFG	l _{OUT}	T _{pw} = 25 ms, duty = 20% 7 circuits	0	_ ((200	mA / ch	
		AFG		$T_{\text{DW}} \le 25 \text{ ms}$ 7 circuits $T_i = 120^{\circ}\text{C}$	0		240		
				Ta = 85°C (Note 1) duty = 50%	> 0 <u></u>	7/	60		
Input Voltage —	TD62304AI	PG / AFG	V _{IN}		-20	1	Vcc	V	
	TD62305AI	PG / AFG			0	<u> </u>	5.5	V	
Power Dissipation APG AFG		APG	P _D	- 0	7	_	0.52	W	
		AFG		(Note 1)	J)_	_	0.325		

Note 1: On glass epoxy PCB (30 × 30 × 1.6 mm Cu 50%)

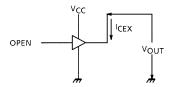
Electrical Characteristics (Ta = 25°C)

				^	~				
CHARACTE	ERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION		MIN	TYP.	MAX	UNIT
Output Leakage Current		CEX	1 (V _{CC} = 5.5 V V _{IN} = 0 V	V _{OUT} = 50 V Ta = 85°C	_	_	-100	μΑ
Output Saturation Voltage		V _{CE} (sat)	2	V _{CG} = 4.5 V I _{OUT} = 350 mA	V _{IN} = V _{IN} (ON) MAX.	_	1.4	2.0	٧
Input Current	(Output On)	I _{IN} (ON)	3	V _{CC} = 5.5 V, V _{IN} = 0.4 V		_	-0.32	-0.45	mA
				V _{CC} = 5.5 V, V _{IN} = -20 V		_	_	-2.6	
	(Output Off)	I _{IN (QFF)}	4	_		_	_	-40	μΑ
Input Voltage (Output On)	TD62304		5	_		_	_	V _{CC} -2.8	٧
	TD62305	VIN (ON)	5			_	_	V _{CC} -3.7	
Supply Current –	(Output On)	(ec (on)	6	V _{CC} = 5.5 V, V _{IN} = 0 V		_	17	22	mA
	(Output Off)	I _{CC} (OFF)	6	V _{CC} = V _{IN} = 5.5 V		_	_	100	μΑ
Turn-On Delay		ton	7	V _{CC} = 5 V.	V _{OUT} = 50 V R _L = 125 Ω	_	0.1	_	
Turn-Off Delay		^t OFF	,	V _{CC} = 5 V, C _L = 15 pF	V _{OUT} = 50 V R _L = 125 Ω	_	3	_	μs

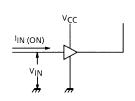
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Test Circuit

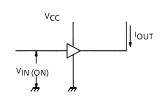
1. I_{CEX}



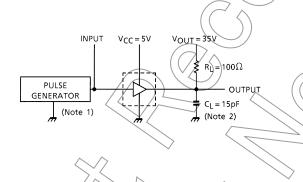
3. I_{IN} (ON)



5. V_{IN (ON)}



7. ton, toff



Note 1: Pulse Width 50 µs, duty cycle 10%

Output impedance 50 Ω , $t_f \le 10$ ns, $t_f \le 5$ ns

Note 2: CL includes probe and jig capacitance.

Precautions for Using

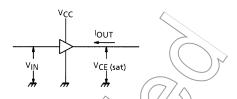
This IC does not include built-in protection circuits for excess current or overvoltage.

If this IC is subjected to excess current or overvoltage, it may be destroyed.

Hence, the utmost care must be taken when systems which incorporate this IC are designed. Utmost care is necessary in the design of the output line, VCC and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

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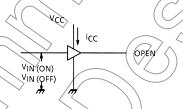
2. hfe, VCE (sat)

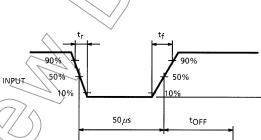


4. I_{IN} (OFF)



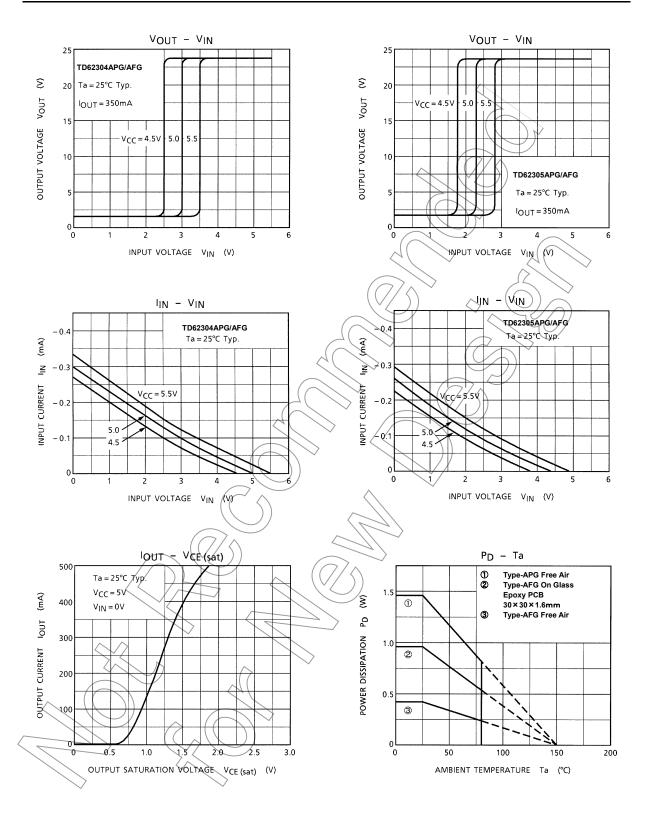
6. lcc





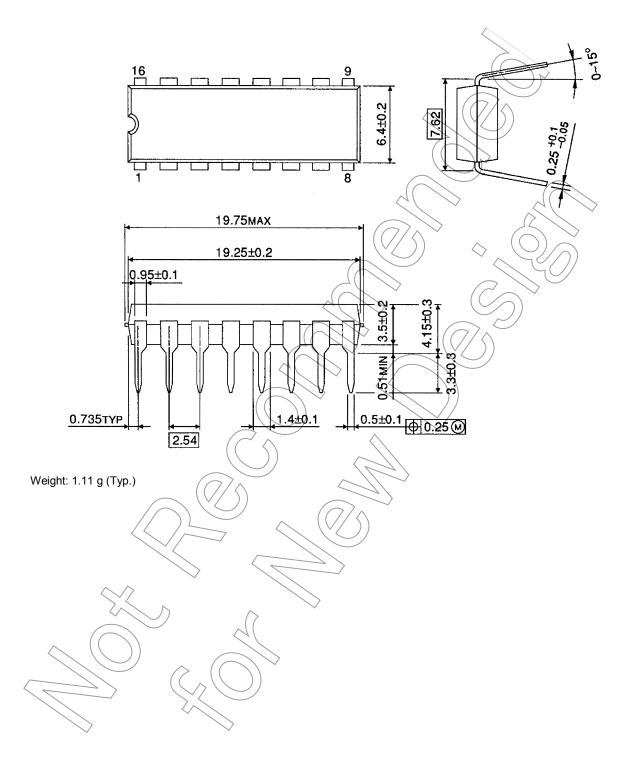
 $V_{IH} = 3V$

OUTPUT 50% VOH



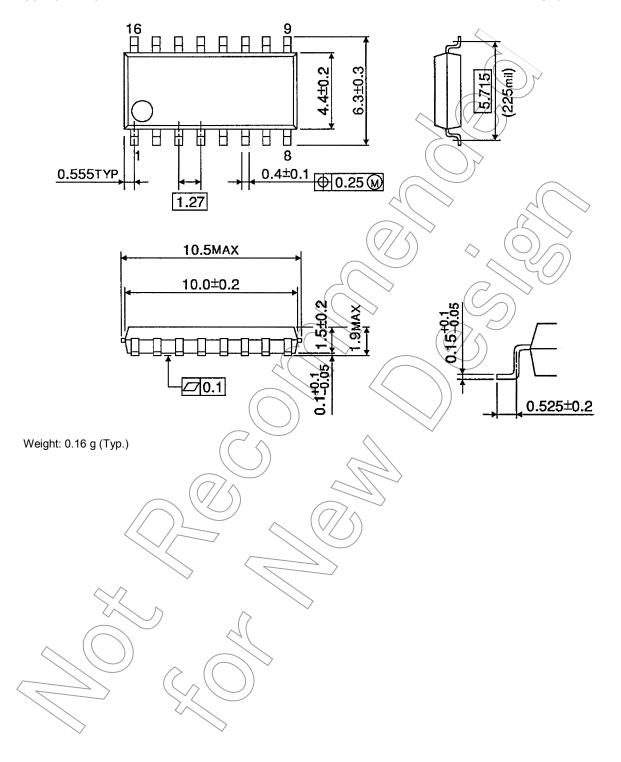
Package Dimensions

DIP16-P-300-2.54A Unit: mm



Package Dimensions

SOP16-P-225-1.27 Unit: mm



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Notes on Contents

1. Equivalent Circuits

The equivalent circuit diagrams may be simplified or some parts of them may be omitted for explanatory purposes.

2. Test Circuits

Components in the test circuits are used only to obtain and confirm the device characteristics. These components and circuits are not guaranteed to prevent malfunction or failure from occurring in the application equipment.

IC Usage Considerations

Notes on Handling of ICs

- (1) The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.

 Exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
- (2) Use an appropriate power supply fuse to ensure that a large current does not continuously flow in case of over current and/or IC failure. The IC will fully break down when used under conditions that exceed its absolute maximum ratings, when the wiring is routed improperly or when an abnormal pulse noise occurs from the wiring or load, causing a large current to continuously flow and the breakdown can lead smoke or ignition. To minimize the effects of the flow of a large current in case of breakdown, appropriate settings, such as fuse capacity, fusing time and insertion circuit location, are required.
- (3) If your design includes an inductive load such as a motor coil, incorporate a protection circuit into the design to prevent device malfunction or breakdown caused by the current resulting from the inrush current at power ON or the negative current resulting from the back electromotive force at power OFF. IC breakdown may cause injury, smoke or ignition.

 Use a stable power supply with ICs with built-in protection functions. If the power supply is unstable, the protection function may not operate, causing IC breakdown. IC breakdown may cause injury, smoke or ignition.
- (4) Do not insert devices in the wrong orientation or incorrectly.

 Make sure that the positive and negative terminals of power supplies are connected properly.

 Otherwise, the current or power consumption may exceed the absolute maximum rating, and exceeding the rating(s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.

 In addition, do not use any device that is applied the current with inserting in the wrong orientation or incorrectly even just one time.
- (5) Carefully select external components (such as inputs and negative feedback capacitors) and load components (such as speakers), for example, power amp and regulator.

 If there is a large amount of leakage current such as input or negative feedback condenser, the IC output DC voltage will increase. If this output voltage is connected to a speaker with low input withstand voltage, overcurrent or IC failure can cause smoke or ignition. (The over current can cause smoke or ignition from the IC itself.) In particular, please pay attention when using a Bridge Tied Load (BTL) connection type IC that inputs output DC voltage to a speaker directly.



Points to Remember on Handling of ICs

(1) Heat Radiation Design

In using an IC with large current flow such as power amp, regulator or driver, please design the device so that heat is appropriately radiated, not to exceed the specified junction temperature (Tj) at any time and condition. These ICs generate heat even during normal use. An inadequate IC heat radiation design can lead to decrease in IC life, deterioration of IC characteristics or IC breakdown. In addition, please design the device taking into considerate the effect of IC heat radiation with peripheral components.

(2) Back-EMF

When a motor rotates in the reverse direction, stops or slows down abruptly, a current flow back to the motor's power supply due to the effect of back-EMF. If the current sink eapability of the power supply is small, the device's motor power supply and output pins might be exposed to conditions beyond absolute maximum ratings. To avoid this problem, take the effect of back-EMF into



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About solderability, following conditions were confirmed

- Solderability
 - (1) Use of Sn-37Pb solder Bath
 - · solder bath temperature = 230°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux
 - (2) Use of Sn-3.0Ag-0.5Cu solder Bath
 - · solder bath temperature = 245°C
 - · dipping time = 5 seconds
 - · the number of times = once
 - · use of R-type flux

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